# Low-loss Microstrip Transmission Line Fabricated With Improved Liftoff Process



Larry A. Hess<sup>a</sup>, Emily M. Barrentine<sup>a</sup>, Ari D. Brown<sup>a</sup>, Aveek Gangopadhyay<sup>a</sup>, Kenneth Livi<sup>b</sup>, Mona Mirzae<sup>a</sup>, S. Harvey Moseley<sup>a</sup>, Omid Noroozian<sup>a</sup>, Thomas R. Stevenson<sup>a</sup>, Eric R. Switzer<sup>a</sup>, Edward J. Wollack<sup>a</sup>, Sang Yoon<sup>a</sup>

<sup>a</sup>NASA-Goddard Space Flight Center, Greenbelt, MD, USA

<sup>b</sup>Johns Hopkins University, Baltimore, MD, USA



Submm ligh

Half-wave Microstrip-line KID

### Abstract

The  $\mu$ -Spec integrated spectrometer operating at ~500 GHz, employs thin film superconducting Nb microstrip transmission lines deposited directly on a thin (450 nm) single-crystal silicon dielectric. This single-crystal silicon layer is chosen as the dielectric layer due to its low intrinsic loss, with the goal of achieving both highefficiency and precise phase control in a compact spectrometer architecture. To avoid roughening or etching through the thin single-crystal silicon dielectric a liftoff technique was developed for patterning these microstrip transmission lines and ground plane structures. This twolayer liftoff process was designed for use with sputter deposition and resulted in a US patent. Although this original technique provided precise control of linewidth, results of initial prototype spectrometer devices and separate diagnostic co-planer waveguide resonator devices showed that unexpected loss was being introduced due to the lift-off process. This extra loss was believed to be due to the "tails" (thin tapered regions) at the edge of the metal traces resulting from the sputtering process, as well as an amorphous oxide layer at the Nb-Si interface. We have since demonstrated an improved lift-off technique, which provides a clean metal-Si interface and removes the loss-inducing tails by a two-step selective etching method. This results in a decrease in microwave loss by more than an order of magnitude when measured in co-planar waveguide microwave resonator structures. We present these microwave test results and also SEM and TEM images of the microstrip interfaces and edge profiles before and after application of the improved process.

# Motivation: High Microwave Loss in $\mu$ -Spec Prototypes

R=64 µ-Spec Prototype:



- μ-Spec is a integrated on-chip submillimeter spectrometer under development for astrophysical applications.
- μ-Spec is an analog to a diffraction-grating spectrometer, implemented on a Si chip with Nb microstrip transmission lines and Al/Nb



• The μ-Spec integrated spectrometer is realized by patterning superconducting Nb on both sides of a low-loss 450 nm thick single-crystal Si device layer of an Silicon-on-Insulator (SOI) wafer, using a flip-bonding process [2].

#### R=64 MKIDs:

prototypes, • In R=64 unexpected microwave loss was observed in the Al/Nb **MKIDs** with maximum internal quality factors Q<sub>i</sub> of only ~40,000 at moderately high readout powers.

• From resonant frequency and Q<sub>i</sub> vs. temperature and readout power VS. dependence, we determined the loss was dominated Two-Level by [3], Systems (TLSs) with tan  $\delta$  parameter ~1.5 x 10<sup>-4</sup>.

microstrip Microwave Kinetic Inductance Detectors (MKIDs).

Prototype R=64 μ-Specs been have demonstrated in the laboratory [1] and R=512 µ-Specs are planned for a cryogenic balloon-borne instrument, EXCLAIM.

• To avoid etching or roughening the Si a precision Nb liftoff process was also developed [2].

• The Nb ground plane also forms the ground plane of the Al/Nb microstrip MKIDs.

• Similar loss was observed in both Al/Nb and Nb/Nb (dark) MKIDs, pointing to groundplane Nb the interface as the source of the high loss.



# Microwave Loss Study

# Nb 0 nm

Si-Nb Interface

Before: TEM image showing the groundplane Nb-Si interface of R=64 μ-Spec an Here prototype. there is evidence of an amorphous layer which would be a source of TLS loss.



1-layer Nb Coplanar-Waveguide (CPW) quarter-wave resonators with a 'fishbone' resonance frequency tuning structures [4] were used for a rapidturn study of the impacts of process variations on microwave internal Q<sub>i</sub>.

- Coupling Q values across the chip range from ~5,000 to ~500,000 and resonance frequencies are at ~3.5 GHz.

### **1-layer Nb CPW Resonator Diagnostic Chip:**



### **Sample Comparison:**

	Sample ID	Device Type	Primary Process Differences	Microwave Q <sub>i</sub>	Microwave Q <sub>i</sub>	Film
n				Readout power:	Readout power:	RRR
м				-130 dBm	-80 dBm	
d	Nb etch	Fishbone CPW	Reactive ion etch of Nb	400,000-1,000,000	200,000-400,000	5.9
	(2 samples)	resonator				
-	Nb R4C3	Fishbone CPW	Nb liftoff	200,000	100,000-150,000	5.7
		resonator	BOE clean prior to deposition			
e			Removal of sidewalls			
S	Nb E06	Fishbone CPW	Nb liftoff	150,000-350,000	100,000-200,000	5.0
		resonator	Reverse bias prior to deposition			
			Removal of sidewalls			

## Summary

- Previous µ-Spec prototypes implemented a non-ideal Nb liftoff process, which resulted in an amorphous oxide layer at the Nb-Si interface, and a tapered sidewall profile, both which negatively impacted the microwave loss and sensitivity of the MKIDs.
- We found a combination of 1) substrate cleaning steps prior to the deposition and 2) a post-liftoff sidewall etch were both necessary to achieve low microwave loss in Nb films patterned into CPW resonators via liftoff.
- We hope to demonstrate high spectrometer efficiency and high internal quality factor microstrip MKIDs in next generation high resolution µ-Specs, which are currently under development for the EXCLAIM (EXperiment for Cryogenic Large-Aperture Intensity Mapping) balloon-borne instrument.

# References

[1] Noroozian, Omid, et al. "µ-Spec: An efficient compact integrated spectrometer for submillimeter astrophysics." 26TH International Symposium on Space Terahertz Technology. 2015. [2] Patel, Amil, et al. "Fabrication of MKIDs for the MicroSpec Spectrometer." IEEE Transactions on Applied Superconductivity 23.3 (2013): 2400404..

[3] Gao, J., The physics of superconducting microwave resonators, Doctoral dissertation, California Institute of Technology, 2008. [4] Stevenson, Thomas R., et al. "Superconducting films for absorbercoupled MKID detectors for sub-millimeter and far-infrared astronomy." IEEE Transactions on Applied Superconductivity 19.3 (2009): 561-564.